
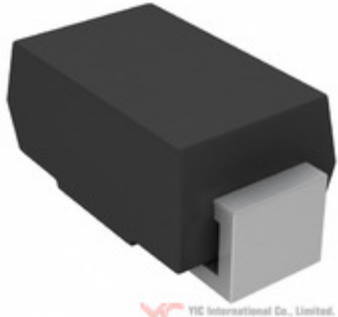
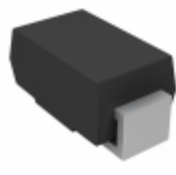
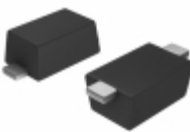
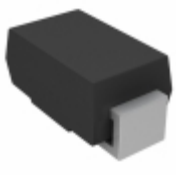

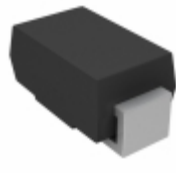

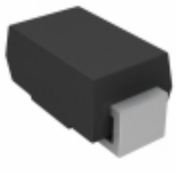
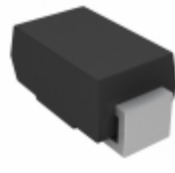
	<p>US1A-M3/61T</p>
	<p>Hersteller-Teilenummer: US1A-M3/61T</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: DIODE GEN PURP 50V 1A DO214AC</p> <p>Datenblätter:  US1A-M3/61T.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 358500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	US1A-M3/61T
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	DIODE GEN PURP 50V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter
Teilstatus	358500 pcs Stock
detaillierte Beschreibung	Diode Standard 50V 1A Surface Mount DO-214AC
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1V @ 1A
Strom - Sperrleckstrom @ Vr	10µA @ 50V
Spannung - Sperr (Vr) (max)	50V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	50ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	15pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

US1A-M3/61T ist neu im Original, Suche US1A-M3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie US1A-M3/61T Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage US1A-M3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>US1A-M3/5AT Vishay / Semiconductor - Diodes Division DIODE 1A 50V 50NS DO-214AC</p>	 <p>US1AFA AMI Semiconductor / ON Semiconductor DIODE GEN PURP 50V 1A SOD123FA</p>	 <p>US1A-E3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1AF Original US1AF Original</p>
 <p>US1A-M3/61T Vishay / Semiconductor - Diodes Division DIODE 1A 50V 50NS DO-214AC</p>	 <p>US1A-TP Micro Commercial Components (MCC) DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1A-E3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 50V 1A DO214AC</p>	 <p>US1A-M3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 1A DO214AC</p>

heiße Teile

Mehr

US168ELD	US168ESE	US1881ESO	US1881KSE	US1881KSO
US1881KUA	US1881KUA-AAA-000-BU	US1881LSO	US1A-13-F	US1A-E3/5AT
US1A-E3/5AT	US1A-E3/61T	US1A-E3/61T	US1A-M3/61T	US1AHE3/5AT
US1AHE3/5AT	US1AHE3/61T	US1AHE3/61T	US1B-13-F	US1B-E3/5AT
US1B-E3/5AT	US1B-E3/61T	US1B-E3/61T	US1B-M3/61T	US1B-M3/61T
US1BHE3/5AT	US1BHE3/5AT	US1BHE3/61T	US1BHE3/61T	US1C-E3/61T
US1D-13-F	US1D-E3/61T	US1D-E3/61T	US1D-M3/61T	US1D-M3/61T
US1DWF-7	US1DWF-7	US1G-13-F	US1G-E3/61T	US1G-E3/61T
US1G-M3/61T	US1G-M3/61T	US1G/11T	US1GHE3/5AT	US1GHE3/5AT
US1GHE3/61	US1GHE3/61T	US1GHE3/61T	US1GHE3_A/H	US1GHE3_A/H

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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